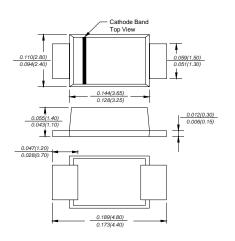


SS32F THRU SS3200F

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 3.0 Ampere

SMAF



Dimensions in inches and (millimeters)

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss,high efficiency
- ◆ Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC SMAF molded plastic body Terminals: leads solderable per MIL-STD-750,

Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.0018 ounce, 0.064 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

			1							
SYMBOLS	SS32F	SS33F	SS34F	SS35F	SS36F	SS38F	SS310F	SS3150F	SS3200F	UNITS
VRRM	20	30	40	50	60	80	100	150	200	VOLTS
VRMS	14	21	28	35	42	56	70	105	140	VOLTS
VDC	20	30	40	50	60	80	100	150	200	VOLTS
3.0									Amp	
I(AV)	5.0									
IFSM	80.0								Amps	
VF	0.55			0.70			0.85		0.95	Volts
	0.5 0.2									mA
IR		20.0	0		10 2.0					
C¹	500			300				pF		
Reja	55.0								°C/W	
TJ,	-50 to +1			125	25			-50 to +150		
Тѕтс	-50 to +150								°C	
	VRRM VRMS VDC I(AV) IFSM VF IR CJ R 0JA TJ,	V _{RRM} 20 V _{RMS} 14 V _{DC} 20 I(aV) IFSM VF IR CJ RθJA TJ,	V _{RRM} 20 30 V _{RMS} 14 21 V _{DC} 20 30 I(AV) IFSM VF 0.55 IR C _J 500 RθJA T _J , -5	VRRM 20 30 40 VRMS 14 21 28 VDC 20 30 40 I(AV) IFSM VF 0.55 IR CJ 500 Reja TJ, -50 to +	V _{RRM} 20 30 40 50 V _{RMS} 14 21 28 35 V _{DC} 20 30 40 50 I(AV) IFSM VF 0.55 IR 0.5 CJ 500 RθJA TJ, -50 to +125	V _{RRM} 20 30 40 50 60 V _{RMS} 14 21 28 35 42 V _{DC} 20 30 40 50 60 I(AV) 3.0 V _F 0.55 0.70 I _R 20.0 0.5 C _J 500 R _{θJA} 55.0 T _J -50 to +125	VRRM 20 30 40 50 60 80 VRMS 14 21 28 35 42 56 VDC 20 30 40 50 60 80 I(AV) 3.0 UF 0.55 0.70 0.5 IR 20.0 0.5 CJ 500 55.0 TJ, -50 to +125 -50 to +125	V _{RRM} 20 30 40 50 60 80 100 V _{RMS} 14 21 28 35 42 56 70 V _{DC} 20 30 40 50 60 80 100 I _(AV) 3.0 V _F 0.55 0.70 0.85 I _R 20.0 10 C _J 500 300 R _θ _{JA} 55.0 T _J -50 to +125 -50 to	V _{RRM} 20 30 40 50 60 80 100 150 V _{RMS} 14 21 28 35 42 56 70 105 V _{DC} 20 30 40 50 60 80 100 150 I(AV) 3.0 WF 0.55 0.70 0.85 IR 20.0 10 2.0 CJ 500 300 RθJA 55.0 -50 to +125 -50 to +150	VRMS

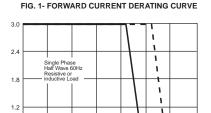
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C. 2.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

RATINGS AND CHARACTERISTIC CURVES SS32F THRU SS3200F



0.6

0 0 25



SS32F-SS36F

SS38F-SS3200F

75

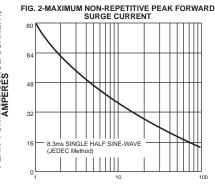


١

175

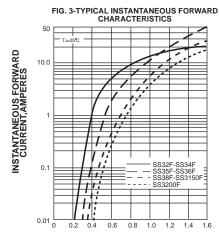
125 150



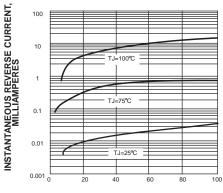


NUMBER OF CYCLES AT 60 Hz

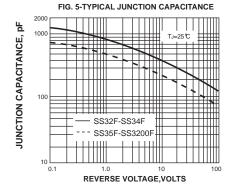
FIG. 4-TYPICAL REVERSE CHARACTERISTICS

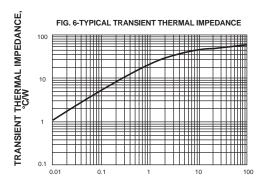












t,PULSE DURATION,sec.